# HIGH ISOLATION X-SPDT (DP4T) SWITCH GaAs MMIC

### ■ GENERAL DESCRIPTION

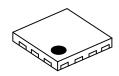
The NJG1690MD7 is a GaAs X (cross)-SPDT(DP4T) switch MMIC for switching of balanced (differential) dual band filters. It features low insertion loss and very high isolation for balanced signal input which makes it much suited for balanced filter switching.

The ESD protection circuit are integrated in the IC to achieve high ESD tolerance.

The ultra-small and ultra-thin EQFN14-D7 package is adopted.

\*) X-SPDT is a paired SPDT switch controlled synchronously. The X-SPDT includes two SPDT switches whose RF lines have a crossing inside the chip.

PACKAGE OUTLINE



NJG1690MD7

APPLICATIONS Balanced filter switching application TDD/FDD LTE, UMTS, CDMA and GSM Multi-mode or Multi-band applications Mobile phone, Tablet PC, Data card, Router and others mobile device applications

### **■** FEATURES

Low operation voltage	V <sub>DD</sub> =2.7V	
Low control voltage	V <sub>CTL(H)</sub> =1.8\	/ typ.
High isolation	37dB typ.	@f=2.7GHz, P <sub>IN</sub> =0dBm (with balanced mode operation)
	29dB typ.	@f=1.0GHz, P <sub>IN</sub> =0dBm
	24dB typ.	@f=2.0GHz, P <sub>IN</sub> =0dBm
	21dB typ.	@f=2.7GHz, P <sub>IN</sub> =0dBm
Low insertion loss	0.3dB typ.	@f=1.0GHz, P <sub>IN</sub> =0dBm
	0.4dB typ.	@f=2.0GHz, P <sub>IN</sub> =0dBm
	0.45dB typ.	@f=2.7GHz, P <sub>IN</sub> =0dBm
<ul> <li>Small and thin package</li> </ul>	EQFN14-D7	' (Package size: 1.6x1.6x0.397mm typ.)
RoHS compliant and Halog	gen Free	

• MSL: 1

### ■ PIN CONFIGURATION

11 10	9 8
14-0 0	م م`م`ه_
	3 4

(Ton View)

Pin connection 1. GND 10. PC1 PA2 11. GND 2. PB1 12. VCTL 3. GND 13. GND 4. 5. PB2 14. PA1 6. GND VDD 7. 8. GND 9. PC2

### ■ TRUTH TABLE

"H"=V<sub>CTL(H)</sub>, "L"=V<sub>CTL(L)</sub>

ON PATH	VCTL
PC1-PA1, PC2-PA2	Н
PC1-PB1, PC2-PB2	L

NOTE: Please note that any information on this catalog will be subject to change.

### ■ ABSOLUTE MAXIMUM RATINGS

 $(T_a = +25^{\circ}C, Z_s = Z_l = 50\Omega)$ 

			$(1_a - 1200, Z_s - 100)$	2 -3032)
PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNITS
RF input power	P <sub>IN</sub>	V <sub>DD</sub> =2.7V, VCTL=0V/1.8V	28	dBm
Supply voltage	$V_{DD}$		5.0	V
Control voltage	V <sub>CTL</sub>		5.0	V
Power dissipation	P <sub>D</sub>	Four-layer FR4 PCB with through-hole (74.2x74.2mm), Tj=150°C	1300	mW
Operating temp.	T <sub>opr</sub>		-40~+85	°C
Storage temp.	T <sub>stg</sub>		-55~+150	°C

### ■ ELECTRICAL CHARACTERISTICS

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply voltage	$V_{DD}$		1.5	2.7	4.5	V
Operating current	I <sub>DD</sub>	P <sub>IN</sub> =0dBm	-	16	30	μA
Control voltage (LOW)	$V_{\text{CTL}(L)}$		0	-	0.4	V
Control voltage (HIGH)	V <sub>CTL(H)</sub>		1.3	1.8	4.5	V
Control current	I <sub>CTL</sub>	f=2GHz, P <sub>IN</sub> =0dBm	-	5	10	μA
Insertion loss 1	LOSS1	f=1GHz, P <sub>IN</sub> =0dBm	-	0.30	0.45	dB
Insertion loss 2	LOSS2	f=2GHz, P <sub>IN</sub> =0dBm	-	0.40	0.55	dB
Insertion loss 3	LOSS3	f=2.7GHz, P <sub>IN</sub> =0dBm	-	0.45	0.65	dB
Balanced mode isolation *Note1	B-ISL	PC-PA (PC-PB ON) PC-PB (PC-PA ON) f=2.7GHz, P <sub>IN</sub> =0dBm	33	37	-	dB
Isolation 1	ISL1	PC1-PA1, PC2-PA2 PC1-PB1, PC2-PB2 f=1GHz, P <sub>IN</sub> =0dBm	27	29	-	dB
Isolation 2	ISL2	PC1-PA1, PC2-PA2 PC1-PB1, PC2-PB2 f=2GHz, P <sub>IN</sub> =0dBm	21	24	-	dB
Isolation 3	ISL3	PC1-PA1, PC2-PA2 PC1-PB1, PC2-PB2 f=2.7GHz, P <sub>IN</sub> =0dBm	18	21	-	dB
Isolation 4	ISL4	PC1-PC2 port f=2GHz, P <sub>IN</sub> =0dBm	22	25	-	dB

### Note1:

The balanced mode isolation is a unique specification for isolation defined under the condition where the X-SPDT switch is used in balanced mode operation as shown in application circuit2.

The NJG1690MD7 is designed so that the isolation in the balanced mode operation is much higher than the isolation in the single-ended mode operation.

### ■ ELECTRICAL CHARACTERISTICS

(General conditions:  $T_a$ =+25°C,  $Z_s$ = $Z_l$ =50 $\Omega$ ,  $V_{DD}$ =2.7V,  $V_{CTL(L)}$ =0V,  $V_{CTL(H)}$ =1.8V, with application circuit1)

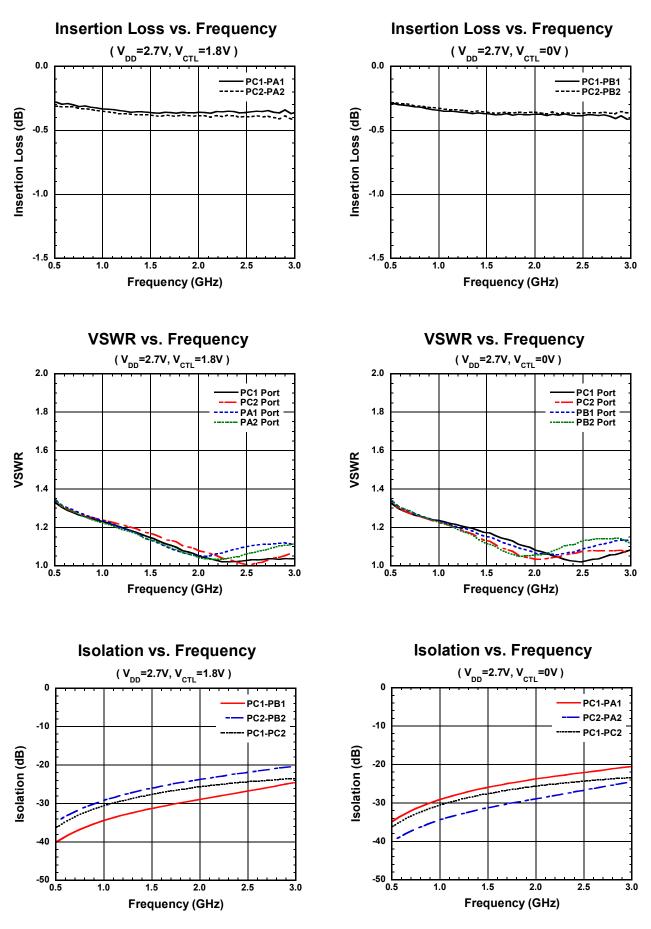
PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input power at 0.2dB compression point	$P_{\text{-0.2dB}}$	f=2GHz	20	24	-	dBm
VSWR	VSWR	f=2GHz, On port	-	1.2	1.4	
Switching time	T <sub>sw</sub>	50% CTL to 10%/90% RF	-	1.5	5.0	μs

# NJG1690MD7

### ■ TERMINAL INFORMATION

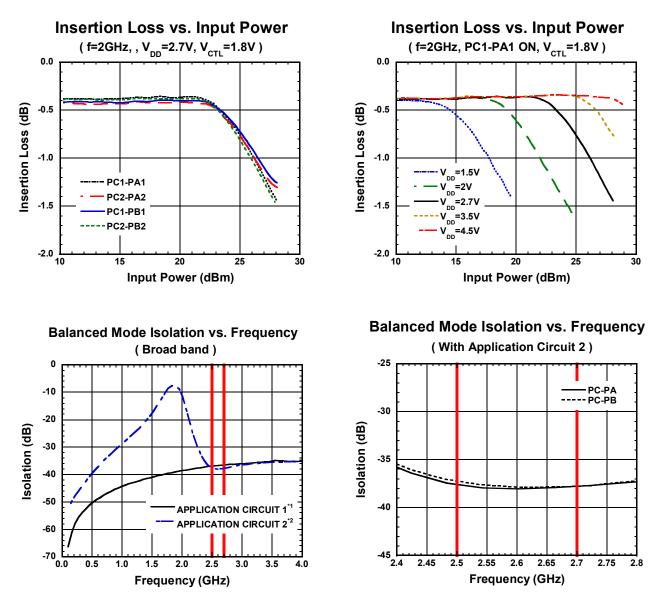
No.	SYMBOL	DESCRIPTION
1	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for good RF performance.
2	PA2	This port is connected to PC2 terminal by applying High-level (1.3~4.5V) at VCTL terminal. An external capacitor is required to block DC voltage of internal circuit.
3	PB1	This port is connected to PC1 terminal by applying Low-level (0~0.4V) at VCTL terminal. An external capacitor is required to block DC voltage of internal circuit.
4	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for good RF performance.
5	PB2	This port is connected to PC2 terminal by applying Low-level (0~0.4V) at VCTL terminal. An external capacitor is required to block DC voltage of internal circuit.
6	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for good RF performance.
7	VDD	A supply voltage terminal (1.5~4.5V). Please place a bypass capacitor between this terminal and GND for avoiding RF noise from outside.
8	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for good RF performance.
9	PC2	Common RF port. This port is connected with either of PA2 or PB2. An external capacitor is required to block DC voltage of internal circuit.
10	PC1	Common RF port. This port is connected with either of PA1 or PB1. An external capacitor is required to block DC voltage of internal circuit.
11	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for good RF performance.
12	VCTL	Control signal input terminal. This terminal is set to high-level (1.3V~4.5V) or low-level (0~0.4V).
13	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for good RF performance.
14	PA1	This port is connected to PC1 terminal by applying High-level (1.3~4.5V) at VCTL terminal. An external capacitor is required to block DC voltage of internal circuit.

■ ELECTRICAL CHARACTERISTICS (With Application circuit1, Loss of external circuit are excluded)



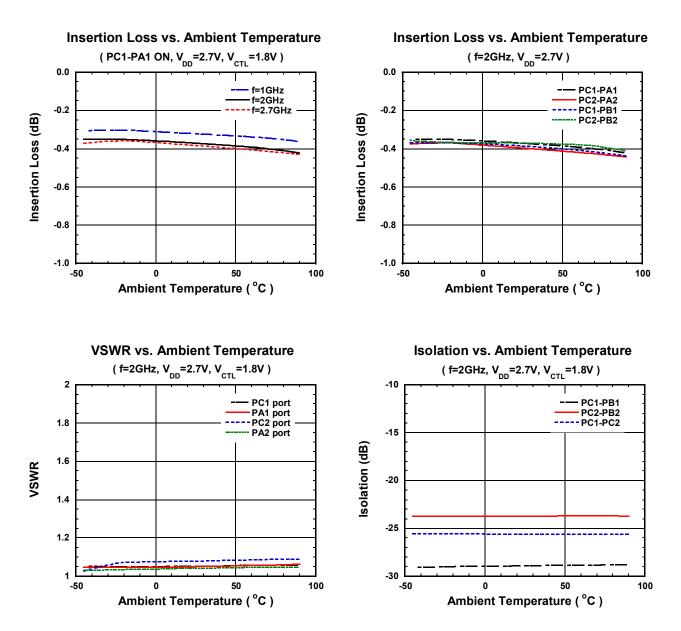
### ELECTRICAL CHARACTERISTICS

(With Application circuit1 and 2, Loss of external circuit are excluded)

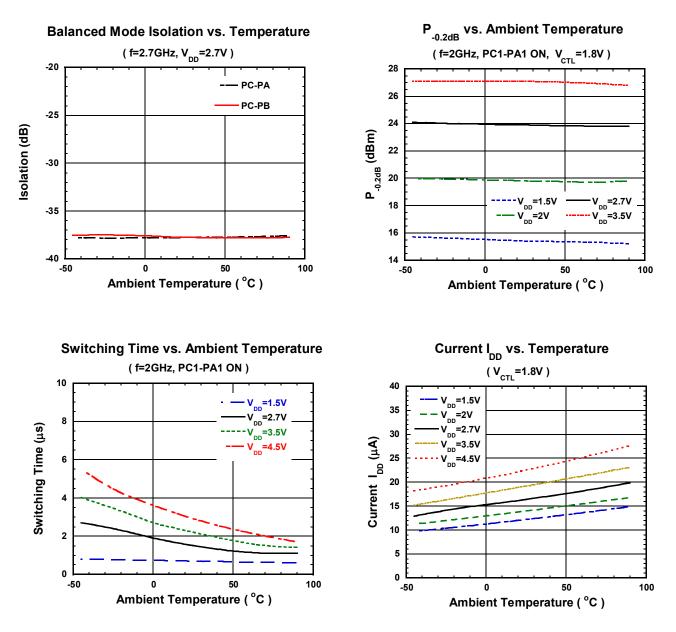


- \*1) The balanced mode isolation measured with the application circuit1.
- \*2) The balanced mode isolation measured with the application circuit2 having single-ended interfaces and baluns.

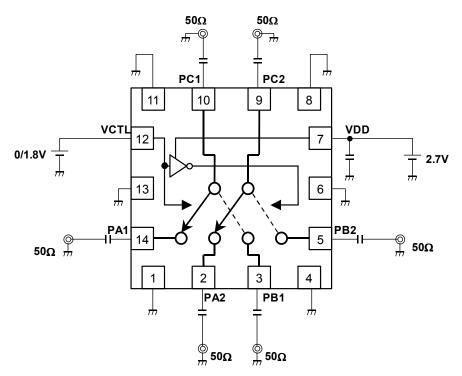
■ ELECTRICAL CHARACTERISTICS (With Application circuit1, Loss of external circuit are excluded)



ELECTRICAL CHARACTERISTICS (With Application circuit1, Loss of external circuit are excluded)

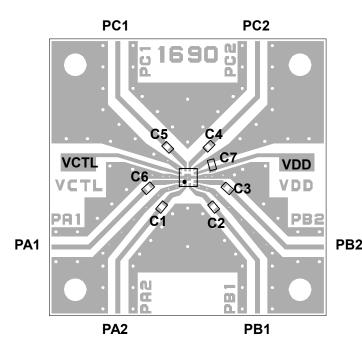


### ■ APPLICATION CIRCUIT 1 (Unbalanced mode)



PCB LAYOUT 1

(TOP VIEW)



PCB:FR-4, t=0.2mmCapacitor Size:1005Strip Line Width:0.4mmPCB Size:26 x 26mm

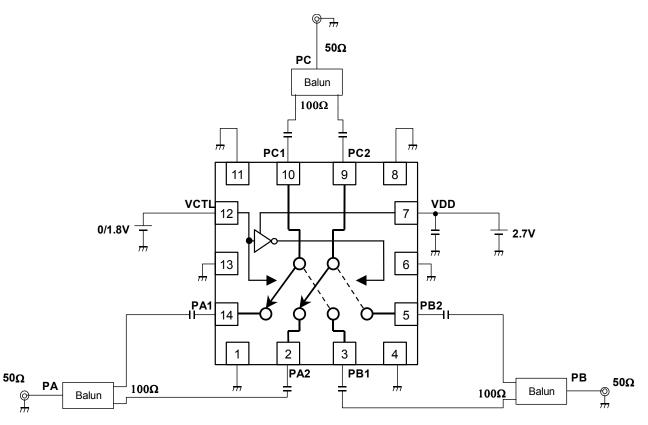
Losses of PCB, capacitors and connectors

	Frequency (GHz)	Loss (dB)
	1	0.35
2	2	0.54
	2.7	0.68

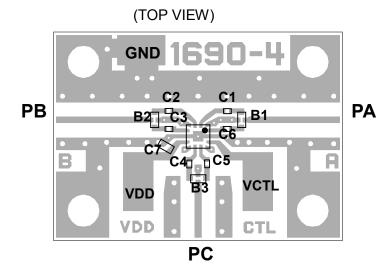
■ PARTS LIST 1

PART ID	Value	COMMENT
C1~C6	56pF	MURATA (GRM15)
C7	1000pF	MURATA (GRM15)

### ■ APPLICATION CIRCUIT 2 (BALANCED MODE)



### PCB LAYOUT 2



PCB:	FR-4, t=0.2mm
Capacitor Size:	0603, 1005
Strip Line Width:	0.4mm
PCB Size:	19.4 x 14mm

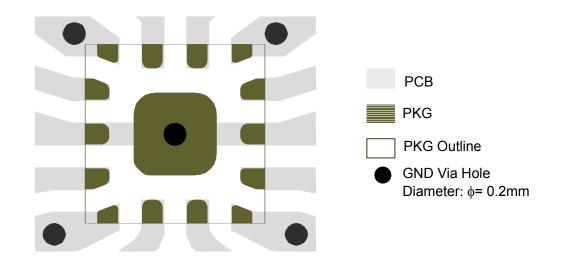
Losses of PCB, capacitors, connectors and baluns

Frequency (GHz)	Loss (dB)
2.7	0.93

### ■ PARTS LIST 2

PART ID	Value	COMMENT
C1~C6	56pF	MURATA (GRM03)
C7	1000pF	MURATA (GRM15)
B1~B3	2500MHz band	TDK-EPC (HHM1903A1)

### PCB LAYOUT FOR EQFN14-D7



### ■ PRECAUTIONS

[1] For good RF performance, all GND terminals must be connected to PCB ground plane of substrate, and via-holes for GND should be placed near the IC.

[2] For good RF performance, through-holes for GND should be placed close to the GND pin 6 and pin 13. One of the ways to do this is to place a via-hole at the TAB pad under this IC.

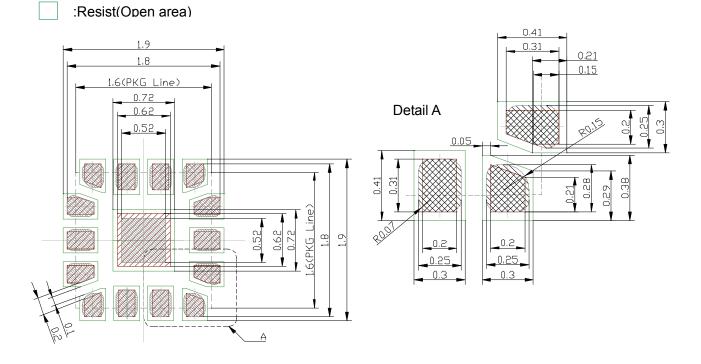
### RECOMMENDED FOOTPRINT PATTERN (EQFN14-D7 PACKAGE Reference)



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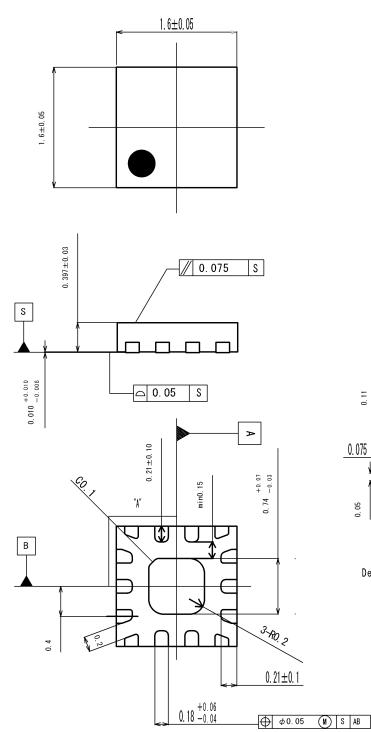
:Mask (Open area) \*Metal mask thickness : 100µm

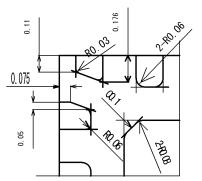
PKG: 1.6mm x 1.6mm Pin pitch: 0.4mm



# NJG1690MD7

### PACKAGE OUTLINE (EQFN14-D7)





Details of  $\ensuremath{\ensuremath{\mathsf{A}}}\xspace$  part (  $\times$  2 )

Units	: mm
Board	: Cu
Terminal treat	: SnBi
Molding material	: Epoxy resin
Weight	: 3.4mg

#### Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

[CAUTION] The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.



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